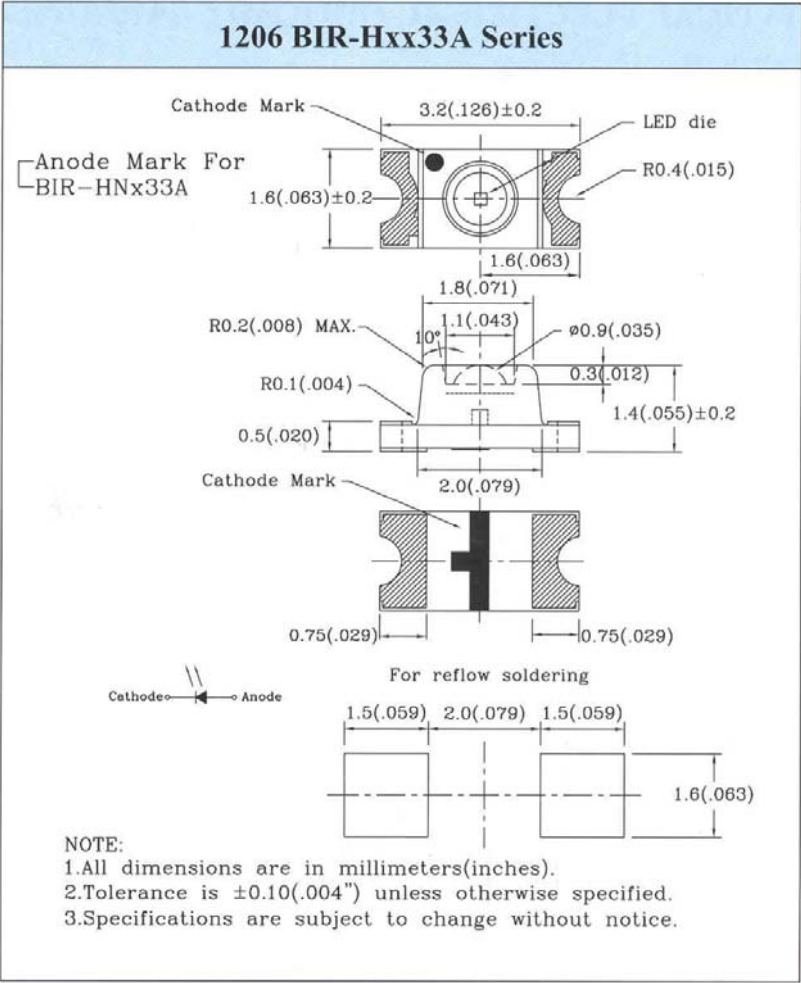


SURFACE MOUNT INFRARED EMITTING DIODES



Absolute Maximum Ratings (Ta=25°C)

	UNIT	SPEC.
IF	mA	30
I _{FP}	A	1.0
VR	V	5
Topr	°C	-25~+80
Tstg	°C	-30~+85

Part No.	Chip			Lens Appearance	Electro-Optical Data (At 20mA)					Viewing Angle 2θ 1/2 (deg)		
	Material	λ _p (nm)	Δλ (nm)		V _f (V)		I _r (uA)	Radiant Power P _o (mw/sr)			T _r (ns)	T _f (ns)
					Typ.	Max.		Min.	Typ.			
BIR-HL033A	GaAs	940	50	Water Clear	1.2	1.7	50	0.71	2.00	500	200	70
BIR-HM133A	GaAlAs	940	50		1.2	1.7	50	1.00	4.00	500	200	
BIR-HN033A	GaAlAs	880	50		1.4	2.0	50	0.71	1.20	500	200	
BIR-HO033A	GaAlAs	850	50		1.4	2.0	50	1.98	4.00	500	200	
BIR-HO133A	GaAlAs	850	50		1.4	2.0	50	1.41	3.00	500	200	